NSN 5961-00-574-3779

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-574-3779
Inclosure Material:
Metal
Overall Length:
0.784 inches
Overall Diameter:
0.505 inches
Internal Configuration:
Junction contact
Mounting Method:
Press fit
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 off-state voltage, rms total
Current Rating Per Characteristic:
35.00 amperes forward current, total rms megawatts
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnpn
Terminal Type And Quantity:
2 tab, solder lug and 1 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0